## Large Active Area InGaAs Quadrants

FCI-InGaAs-QXXX series are large active area InGaAs photodiodes segmented into four separate active areas. These photodiodes come in 1 mm and 3 mm active area diameter. The $\operatorname{InGaAs}$ Quad series with high response uniformity and the low cross talk between the elements are ideal for accurate nulling or centering applications as well as beam profiling applications. They exhibit excellent responsivity from 1100 nm to 1620 nm , and are stable over time and temperature, and fast response times necessary for high speed or pulse operation. The photodiodes are packaged in isolated TO-5 or TO-8 cans with a broadband double sided AR coated flat window, and also can be mounted on ceramic substrate per request.

## Absolute Maximum Ratings

| PARAMETERS | SYMBOL | MIN | MAX | UNITS |
| :--- | :---: | :---: | :---: | :---: |
| Storage Temperature | $\mathrm{T}_{\text {stg }}$ | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| Operating Temperature | $\mathrm{T}_{\text {op }}$ | -40 | +75 | ${ }^{\circ} \mathrm{C}$ |
| Soldering Temperature | $\mathrm{T}_{\text {sld }}$ | --- | +260 | ${ }^{\circ} \mathrm{C}$ |

- APPLICATIONS
- Position Sensoring
- Beam Alignment
- Beam Profiling
- FEATURES
- High Responsivity
- Low Noise
- Spectral Range 900nm to 1700nm
- Low Crosstalk
- Wide Field of View

Electro-Optical Characteristics (per 1 element)

| PARAMETERS | SYMBOL | CONDITIONS | FCI-InGaAs-Q1000 |  |  | FCI-InGaAs-Q3000 |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| Active Area Diameter | $\mathrm{AA}_{\phi}$ | --- | --- | 1000 | --- | --- | 3000 | --- | $\mu \mathrm{m}$ |
| Responsivity | $\mathrm{R}_{\lambda}$ | $\lambda=1310 \mathrm{~nm}$ | 0.85 | 0.90 | --- | 0.85 | 0.90 | --- | A/W |
|  |  | $\lambda=1550 \mathrm{~nm}$ | 0.90 | 0.95 | --- | 0.90 | 0.95 | --- |  |
| Element Gap | --- | --- | --- | 0.045 | --- | --- | 0.045 | --- | mm |
| Capacitance | $\mathrm{C}_{\mathrm{j}}$ | $\mathrm{V}_{\mathrm{R}}=5.0 \mathrm{~V}$ | --- | --- | 25 | --- | --- | 225 | pF |
| Dark Current | $\mathrm{I}_{\mathrm{d}}$ | $\mathrm{V}_{\mathrm{R}}=5.0 \mathrm{~V}$ | --- | 0.5 | 15 | --- | 2.0 | 100 | nA |
| Rise Time/ <br> Fall Time | $\mathrm{t}_{\mathrm{r}} / \mathrm{t}_{\mathrm{f}}$ | $\begin{gathered} \hline \mathrm{V}_{\mathrm{R}}=5.0 \mathrm{~V}, 50 \Omega \\ 10 \% \text { to } 90 \% \end{gathered}$ | --- | 3 | --- | --- | 24 | --- | ns |
| Crosstalk | --- | $\begin{gathered} \lambda=1550 \mathrm{~nm}, \\ \mathrm{~V}_{\mathrm{R}}=5.0 \mathrm{~V} \end{gathered}$ | --- | --- | 1 | --- | --- | 1 | \% |
| Max. Revervse Voltage | --- | --- | --- | --- | 15 | --- | --- | 10 | V |
| NEP | --- | $\lambda=1550 \mathrm{~nm}$ | --- | $1.20 \mathrm{E}-14$ | --- | --- | $2.50 \mathrm{E}-14$ | --- | $\mathrm{W} / \sqrt{ } \mathrm{Hz}$ |

InGaAs-Q1000


Pin Circle Dia. $=0.230$
Bottom View

| Pinout |  |
| :---: | :---: |
| PIN | Description |
| A1 | ANODE QUADRANT 1 |
| A2 | ANODE QUADRANT 2 |
| A3 | ANODE QUADRANT 3 |
| A4 | ANODE QUADRANT 4 |
| C | COMMON CATHODE |

InGaAs-Q3000


| Pinout |  |
| :---: | :---: |
| PIN | Description |
| A1 | ANODE QUADRANT 1 |
| A2 | ANODE QUADRANT 2 |
| A3 | ANODE QUADRANT 3 |
| A4 | ANODE QUADRANT 4 |
| C | COMMON CATHODE |
| SD | SUCTION DIODE |

Notes:

- All units in inches (mm).

